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# **LED Simulation**

In the following example we are going to show how the spectra of a Light Emitting Diode (LED) can be calculated with the **nextnano++** software.

## **Physics model**

In an LED the photons are emitted in the radiative recombination process,

$$R_{\rm p} = c_{\rm p} (n p - n_i^2),$$

where  $R_{\rm m}$  is the local spontaneous emission rate,  $n\$  and  $p\$  correspond to the density of the electrons and the holes in the volume element, and  $n_i\$  is the intrinsic density of the charge carriers.  $R_{\rm m}\$  depends on position  $x\$  because the densities depend on position. The bimolecular recombination coefficient  $c_{\rm m}\$  is a material dependent constant and has units  $c_{\rm m}\$ 

This recombination rate is coupled into the drift-diffusion equation and the stationary solution of the problem,

```
\frac{rm d}{{rm d}t}n = 0,$$
```

is calculated.

#### Spectrum of the emission

According to this simple model, where \$c\_{\rm rad}\$ is just a material constant, the radiative recombination rate, which generates photons of energy \$E {\rm rad}\$ can be written in the form,

where  $n(E_e)$  and  $p(E_h)$  are the electron and hole densities of the energy level  $E_e$  and  $E_h$  in the volume element.

In order to get the spectra of the emission the integral should be calculated for each volume element, and integrated over volume. This simple model uses the bulk material constant  $c_{\text{volume}}$ . However, this approach is not correct for **QW** structures. Additionally, the re-absorption of photons is not included.

## Input file structure

#### **Drift-Diffusion Calculation**

currents{

```
mobility model
                     = constant
   recombination model{
     SRH
                    = no
                                # Shockley-Read-Hall recombination
                    = no
                              # Auger recombination
     Auger
                               # radiative recombination (direct
     radiative
                    = yes
recombination)
   }
   output_fermi_levels{}
   output_currents{}
}
```

We have to include radiative recombination in the drift-diffusion equation in order to take into account the spontaneous emission rate.

```
radiative = yes # radiative recombination (direct
recombination)
```

#### **Density Calculation**

```
classical{
   Gamma{}
   LH{}
   HH{}
   S0{}
   output_bandedges{ averaged = no }
   output carrier densities{}
   output intrinsic density{}
   energy_distribution{
                                      # Calculation of carrier densities as a
function of energy
   min = -5
                                 # Integrate from
    max = 5
                                  # Integrate to
                                  # Integration resolution
    energy resolution = 0.05
   }
}
```

The density has to be calculated in the energy domain, which means we have to define the integration range

```
energy_distribution{  # Calculation of carrier densities as a
function of energy
  min = -5  # Integrate from
  max = 5  # Integrate to
  energy_resolution = 0.05  # Integration resolution
}
```

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# **Results**

#### **Band structure**

The simulated structure is a **p-i-n** diode. The layers of the heterostructure are p-GaAs - p-AlGaAs - p

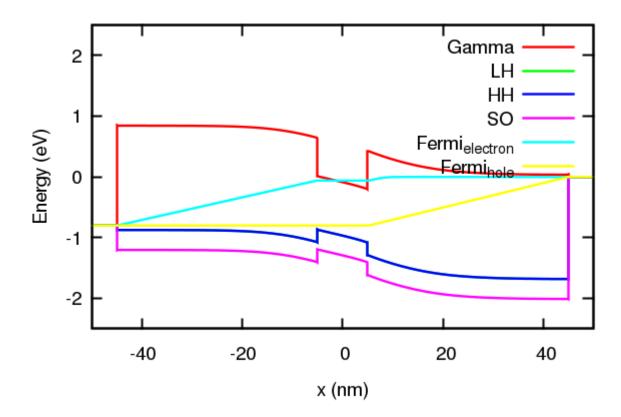


Figure 1: Band edges and quasi-Fermi levels of the p-i-n diode under forward bias

### **Carrier distribution**

The carrier distribution with respect to energy can be seen in figure 2. The density is summed up for the full device. (This means that the position information of the carrier densities is "lost" in this view).

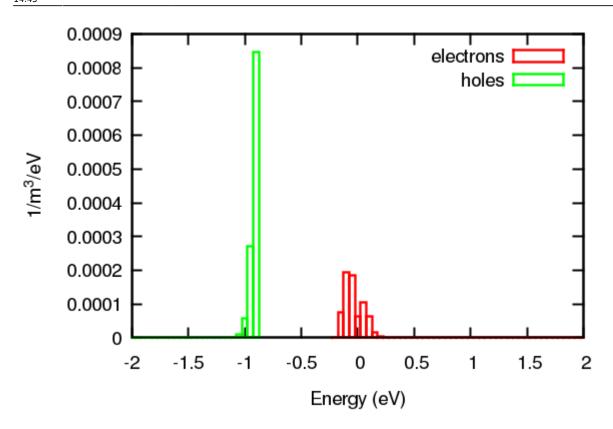


Figure 2: Energy distribution of carriers for the full device volume

# **Emission Spectrum**

The emission spectrum of the LED is plotted in figure 3. The dependence of the spectrum on the bias voltage can be calculated using a voltage sweep.

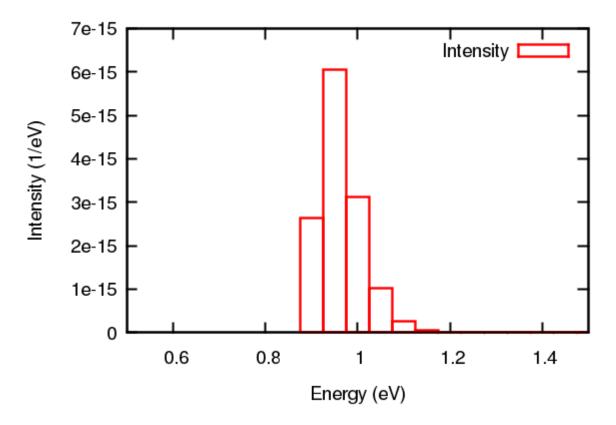


Figure 3: Emission spectrum (Intensity) of the **p-i-n** diode structure in units of 1/eV.

